

Thyristor Modules

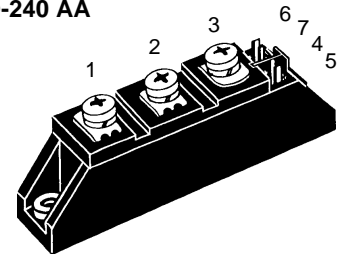
Thyristor/Diode Modules

$$I_{TRMS} = 2x 180 A$$

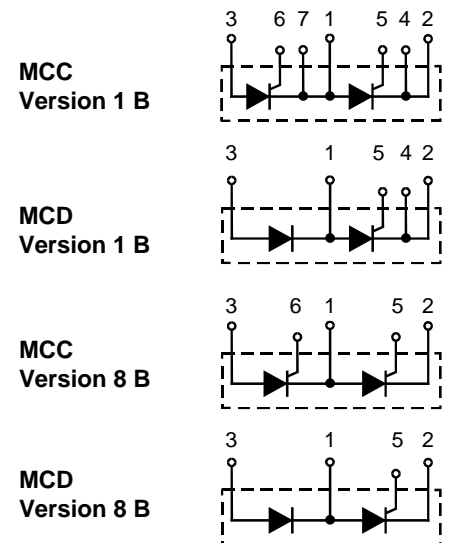
$$I_{TAVM} = 2x 115 A$$

$$V_{RRM} = 800-1800 V$$

V_{RSM} V_{DSM}	V_{RRM} V_{DRM}	Type	
V	V	Version 1 B	Version 8 B
900	800	MCC 72-08io1 B	--
1300	1200	MCC 72-12io1 B	MCD 72-12io1B
1500	1400	MCC 72-14io1 B	--
1700	1600	MCC 72-16io1 B	MCD 72-16io1B
1900	1800	MCC 72-18io1 B	--
		MCC 72-08io8 B	MCD 72-08io8 B
		MCC 72-12io8 B	MCD 72-12io8 B
		MCC 72-14io8 B	MCD 72-14io8 B
		MCC 72-16io8 B	MCD 72-16io8 B
		MCC 72-18io8 B	MCD 72-18io8 B

TO-240 AA


Symbol	Test Conditions	Maximum Ratings	
I_{TRMS}, I_{FRMS} I_{TAVM}, I_{FAVM}	$T_{VJ} = T_{VJM}$ $T_C = 63^\circ C; 180^\circ$ sine $T_C = 85^\circ C; 180^\circ$ sine	180	A
		115	A
		85	A
I_{TSM}, I_{FSM}	$T_{VJ} = 45^\circ C;$ $V_R = 0$ $t = 10$ ms (50 Hz), sine $t = 8.3$ ms (60 Hz), sine	1700	A
		1800	A
	$T_{VJ} = T_{VJM}$ $V_R = 0$ $t = 10$ ms (50 Hz), sine $t = 8.3$ ms (60 Hz), sine	1540	A
		1640	A
$\int i^2 dt$	$T_{VJ} = 45^\circ C$ $V_R = 0$ $t = 10$ ms (50 Hz), sine $t = 8.3$ ms (60 Hz), sine	14 450	A ² s
		13 500	A ² s
	$T_{VJ} = T_{VJM}$ $V_R = 0$ $t = 10$ ms (50 Hz), sine $t = 8.3$ ms (60 Hz), sine	11 850	A ² s
		11 300	A ² s
$(di/dt)_{cr}$	$T_{VJ} = T_{VJM}$ $f = 50$ Hz, $t_p = 200$ μ s $V_D = 2/3 V_{DRM}$ $I_G = 0.45$ A $di_G/dt = 0.45$ A/ μ s	repetitive, $I_T = 250$ A	150 A/ μ s
		non repetitive, $I_T = I_{TAVM}$	500 A/ μ s
$(dv/dt)_{cr}$	$T_{VJ} = T_{VJM};$ $R_{GK} = \infty;$ method 1 (linear voltage rise)	$V_{DR} = 2/3 V_{DRM}$	1000 V/ μ s
P_{GM}	$T_{VJ} = T_{VJM}$ $I_T = I_{TAVM}$	$t_p = 30$ μ s $t_p = 300$ μ s	10 W 5 W
P_{GAV}			0.5 W
V_{RGM}			10 V
T_{VJ}			-40...+125 $^\circ$ C
T_{VJM}			125 $^\circ$ C
T_{stg}			-40...+125 $^\circ$ C
V_{ISOL}	50/60 Hz, RMS $I_{ISOL} \leq 1$ mA	$t = 1$ min $t = 1$ s	3000 V~ 3600 V~
M_d	Mounting torque (M5) Terminal connection torque (M5)		2.5-4.0/22-35 Nm/lb.in. 2.5-4.0/22-35 Nm/lb.in.
Weight	Typical including screws		90 g


Features

- International standard package, JEDEC TO-240 AA
- Direct copper bonded Al₂O₃ -ceramic base plate
- Planar passivated chips
- Isolation voltage 3600 V~
- UL registered, E 72873
- Gate-cathode twin pins for version 1B

Applications

- DC motor control
- Softstart AC motor controller
- Light, heat and temperature control

Advantages

- Space and weight savings
- Simple mounting with two screws
- Improved temperature and power cycling
- Reduced protection circuits

Data according to IEC 60747 and refer to a single thyristor/diode unless otherwise stated. IXYS reserves the right to change limits, test conditions and dimensions

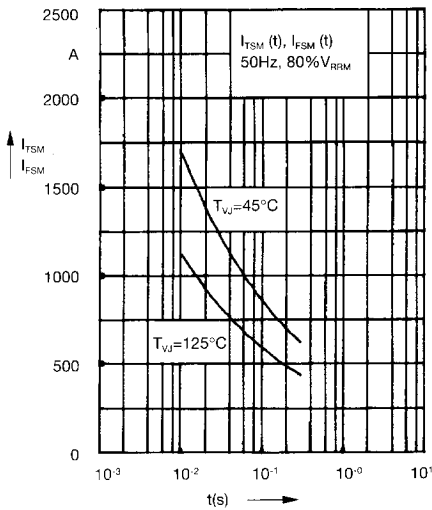


Fig. 3 Surge overload current
 I_{TSM} , I_{FSM} : Crest value, t : duration

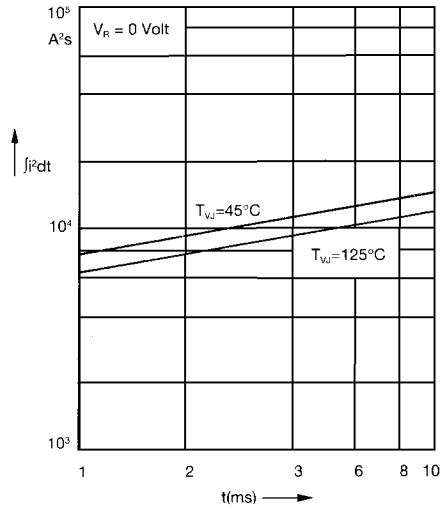


Fig. 4 $\int i^2 dt$ versus time (1-10 ms)

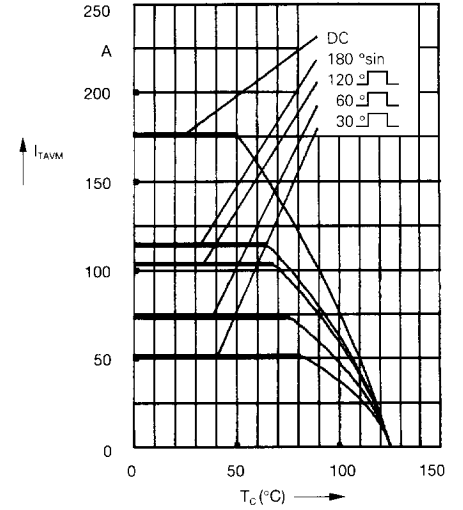


Fig. 4a Maximum forward current at case temperature

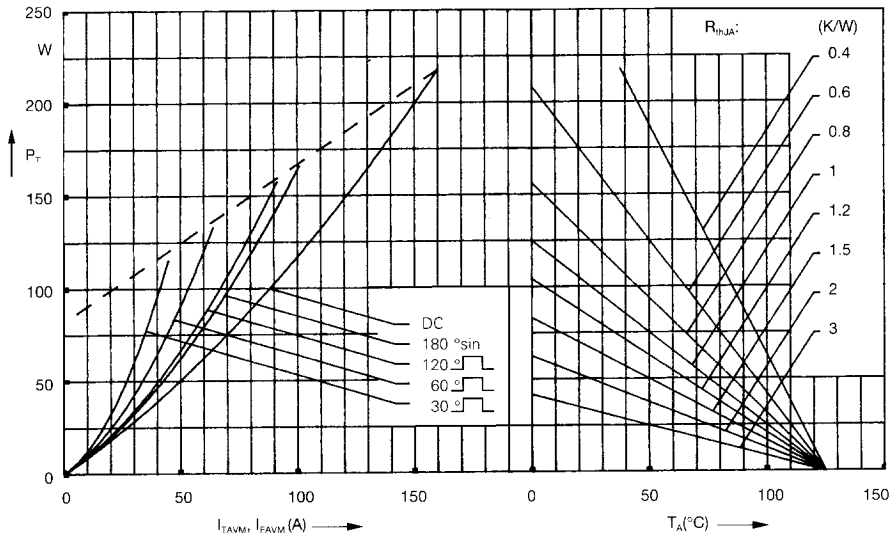


Fig. 5 Power dissipation versus on-state current and ambient temperature (per thyristor or diode)

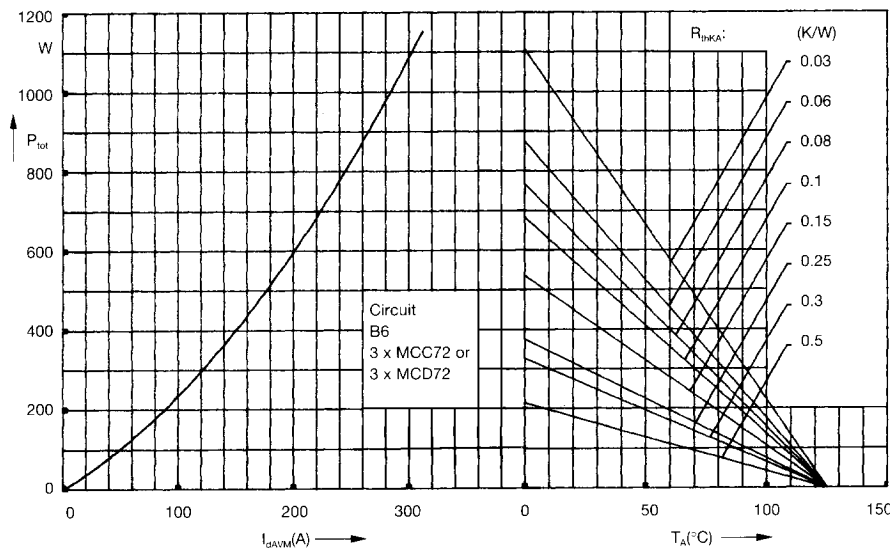


Fig. 6 Three phase rectifier bridge: Power dissipation versus direct output current and ambient temperature

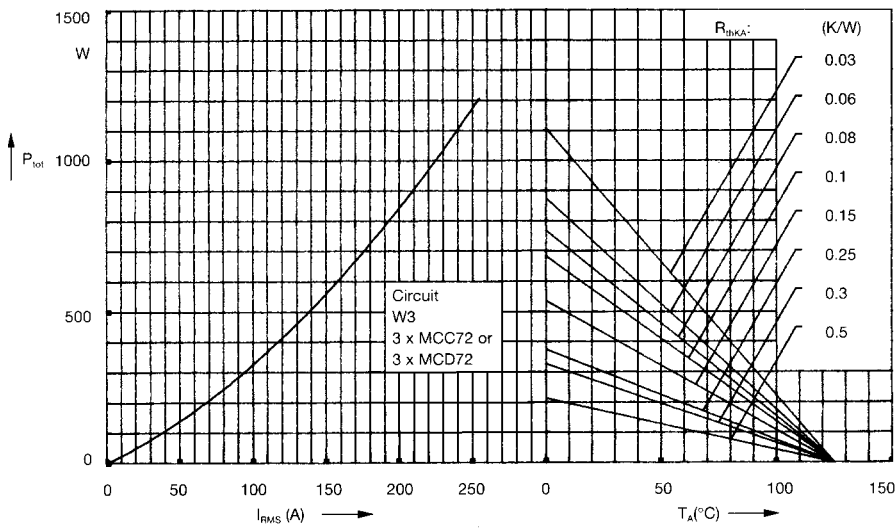


Fig. 7 Three phase AC-controller: Power dissipation versus RMS output current and ambient temperature

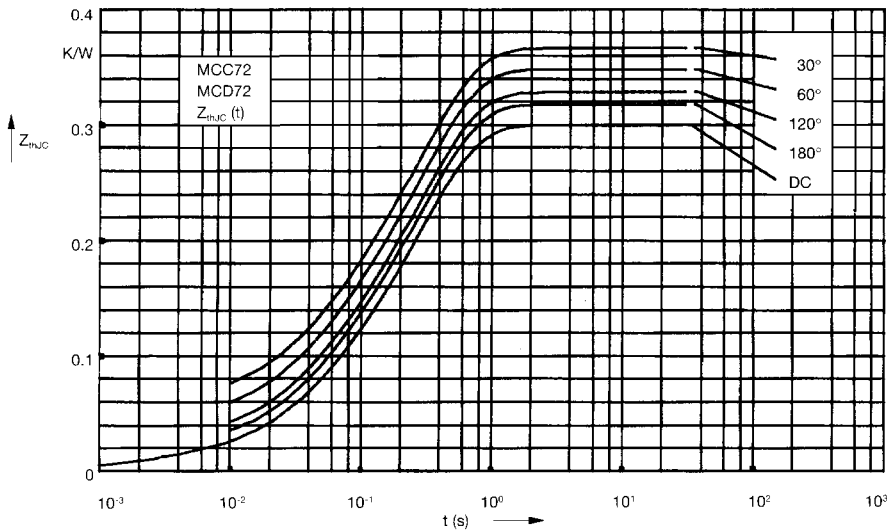


Fig. 8 Transient thermal impedance junction to case (per thyristor or diode)

R_{thJC} for various conduction angles d:

d	R_{thJC} (K/W)
DC	0.3
180°	0.31
120°	0.33
60°	0.35
30°	0.37

Constants for Z_{thJC} calculation:

i	R_{thi} (K/W)	t_i (s)
1	0.008	0.0019
2	0.054	0.047
3	0.238	0.3

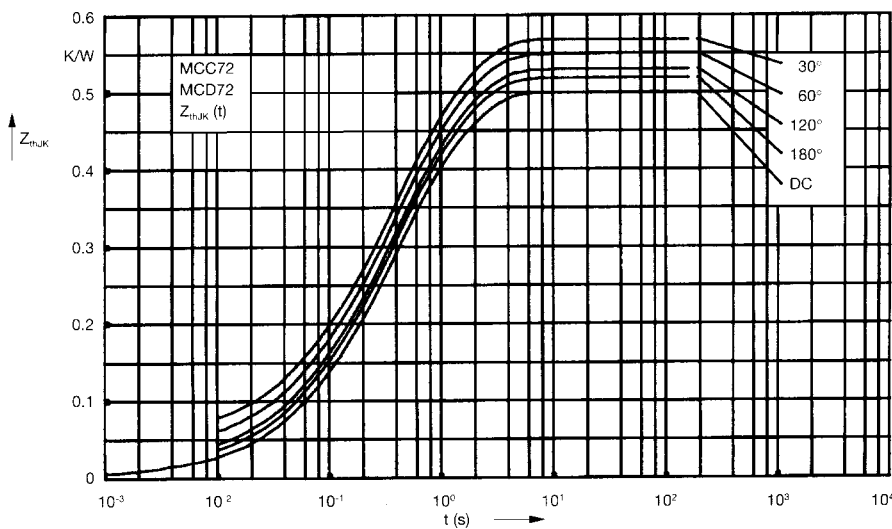


Fig. 9 Transient thermal impedance junction to heatsink (per thyristor or diode)

R_{thJK} for various conduction angles d:

d	R_{thJK} (K/W)
DC	0.5
180°	0.51
120°	0.53
60°	0.55
30°	0.57

Constants for Z_{thJK} calculation:

i	R_{thi} (K/W)	t_i (s)
1	0.008	0.0019
2	0.054	0.047
3	0.238	0.3
4	0.2	1.25